

FEATURES

- ◆ Fast switching for high efficiency
- ◆ Low noise
- ◆ $T_{rr} = 20\text{ns}$
- ◆ Low reverse leakage current
- ◆ High voltage super FRD
- ◆ PFC application

MECHANICAL DATA

- ◆ Case : Molded plastic TO-220AC / TO-220FP
- ◆ Epoxy : UL94V-0 rate flame retardant
- ◆ Terminals : Solder able per MIL-STD-202 method 208
- ◆ Mounting position : Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Symbol	Characteristics	CMPFCD86	Unit
		Rating	
V_{RRM}	Recurrent Peak Reverse Voltage	600	V
V_{RMS}	RMS Voltage	420	V
V_{DC}	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Forward Rectified Current @ $T_c=140^\circ\text{C}$	8.0	A
I_{FSM}	Peak Forward Surge Current 8.3ms single half sine-wave Super imposed on rated load (JEDEC Method)	100	A
I_{FSM}	Peak Forward Surge Current 1.0ms single Square-wave superimposed on rated load (JEDEC Method)	150	A
V_F	Instantaneous Forward Voltage @8A	2.9	V
I_R	DC Reverse Current @ $T_J=25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_J=150^\circ\text{C}$	10	uA
		500	
T_{rr}	Maximum Reverse Recovery Time (note1)	20	nS
C_J	Typical Junction Capacitance (note2)	50	pF
$R_{\theta JC}$	Typical Thermal Resistance (note3)	2.2	$^\circ\text{C}/\text{W}$
I^2t	I^2t Value For Fusing Tp=10ms	91	A^2s
T_J	Operating Temperature Range	-65~175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-65~175	$^\circ\text{C}$

- Notes :** 1. Reverse recovery test conditions $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$
2. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts DC.
3. Thermal Resistance junction to case.

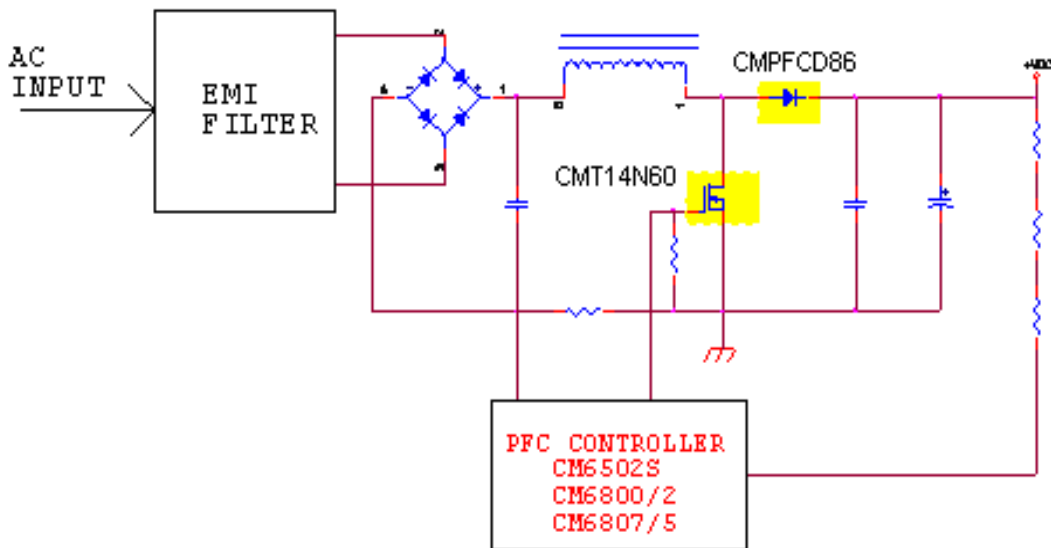
ORDERING INFORMATION

Part Number	Temperature Range	Package
CMPFCD86GN220*	-65°C to 175°C	TO-220AC (Pb Free)
CMPFCD86XN220*	-65°C to 175°C	TO-220AC (HF)
CMPFCD86GN220FP*	-65°C to 175°C	TO-220FP

*Note : G : Suffix for Pb Free Product

X : Suffix for Halogen Free

Application Circuit



TYPICAL CHARACTERISTICS

FIG.1 - FORWARD CURRENT DERATING CURVE

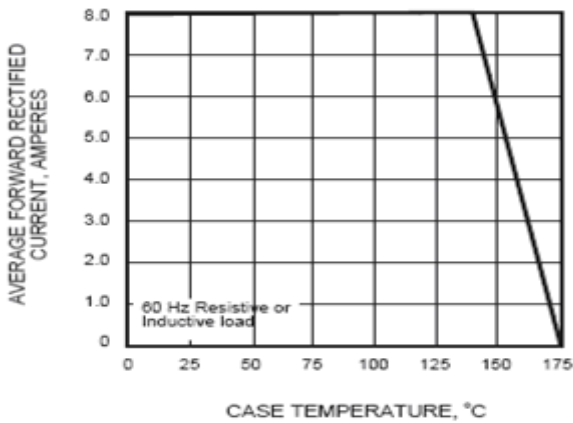


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

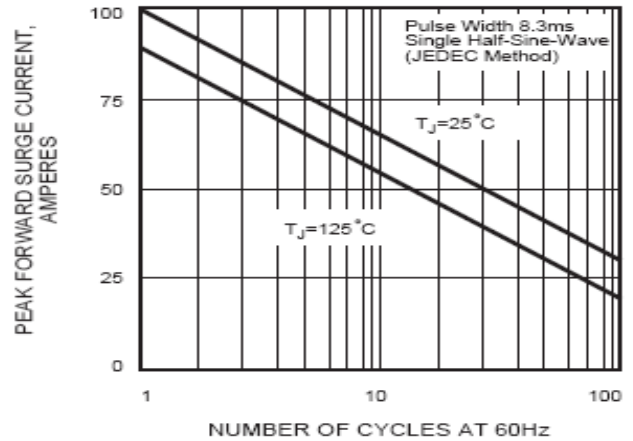


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

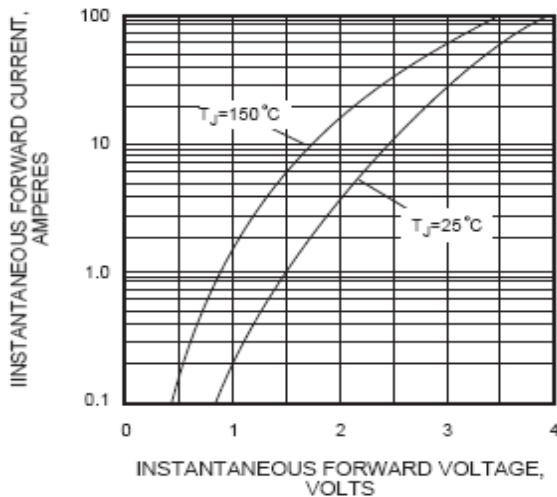


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

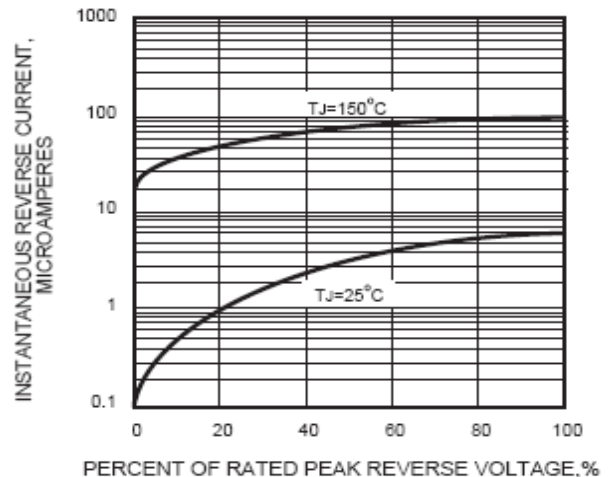


FIG.5 - TYPICAL JUNCTION CAPACITANCE

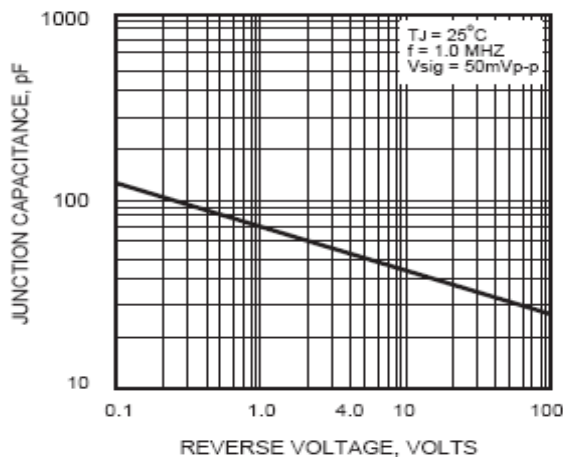
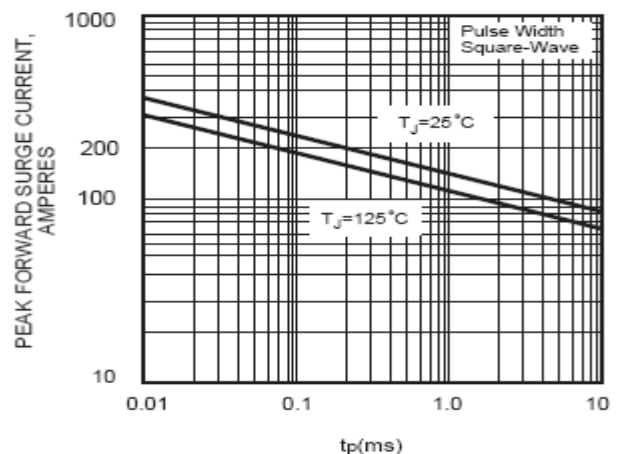
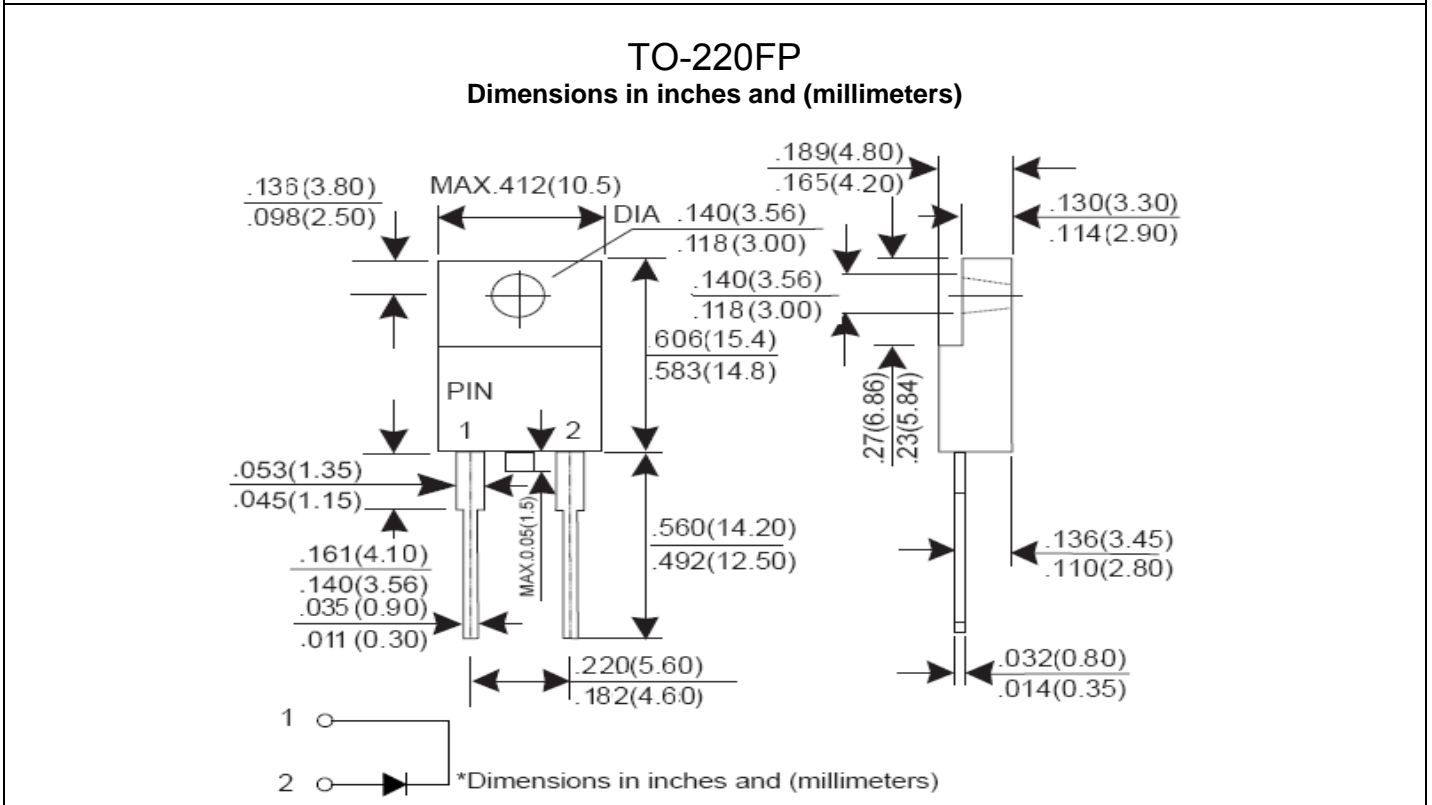
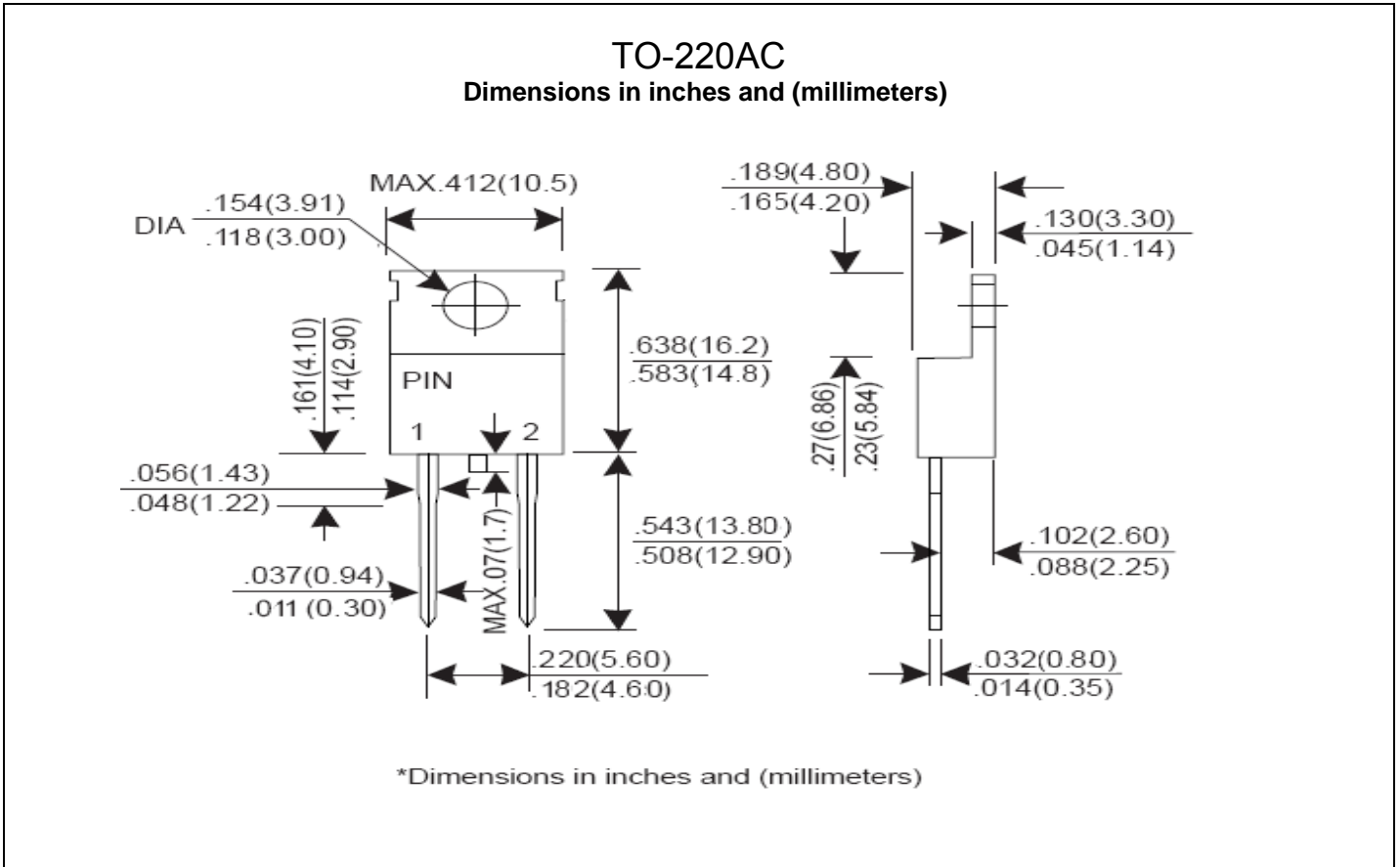


FIG.6 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



PACKAGE DIMENSION



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